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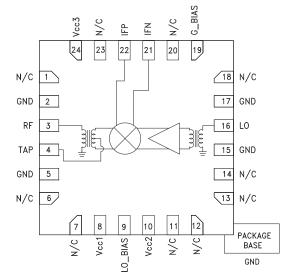


Typical Applications

The HMC687LP4(E) is Ideal for:

- Cellular/3G & LTE/WiMAX/4G
- Basestations & Repeaters
- GSM, CDMA & OFDM
- Transmitters and Receivers

Functional Diagram



BiCMOS MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 1.7 - 2.2 GHz

Features

High Input IP3: +35 dBm 8 dB Conversion Loss @ 0 dBm LO Optimized for High Side LO Input Upconversion & Downconversion Applications Adjustable Supply Current 24 Lead 4x4mm SMT Package: 16mm²

General Description

The HMC687LP4(E) is a high dynamic range passive MMIC mixer with integrated LO amplifier in a 4x4 SMT QFN package covering 1.7 to 2.2 GHz. Excellent input IP3 performance of +35 dBm for down conversion is provided for 3G & 4G GSM/CDMA applications at an LO drive of 0 dBm. With an input 1 dB compression of +23 dBm, the RF port will accept a wide range of input signal levels. Conversion loss is 8 dB typical. The DC to 500 MHz IF frequency response will satisfy GSM/CDMA transmit or receive frequency plans. The HMC687LP4(E) is optimized for high side LO frequency plans and is pin for pin compatible with the HMC685LP4(E) which is a 1.7 - 2.2 GHz converter optimized for low side LO.

Electrical Specifications, $T_4 = +25^{\circ}$ C, IF = 200 MHz, LO = 0 dBm, Vcc = Vcc1, 2, 3 = +5V, G_Bias = +2.5V*

Nominal Supply		Icc = 120 mA Icc =		lcc = 100 mA	Icc = 100 mA Icc = 70 mA		
Parameter	Min.	Тур.	Max.	Тур.	Тур.	Units	
Frequency Range, RF		1.7 - 2.2			GHz		
Frequency Range, LO			1.7 -	2.4		GHz	
Frequency Range, IF		DC - 500 M			MHz		
Conversion Loss		8	10.5	8	8	dB	
Noise Figure (SSB)		8		8	8	dB	
LO to RF Isolation	22	30		32	34	dB	
LO to IF Isolation	22	29		29	31	dB	
RF to IF Isolation	31	42		42	42	dB	
IP3 (Input)		35		34	32	dBm	
1 dB Compression (Input)		23		22	20	dBm	
LO Drive Input Level (Typical)		-3 to +3		-3 to +3	-3 to +3	dBm	
Supply Current Icc total		120	145	100	70	mA	

* Unless otherwise noted all measurements performed as downconverter with high side LO & IF = 200 MHz.

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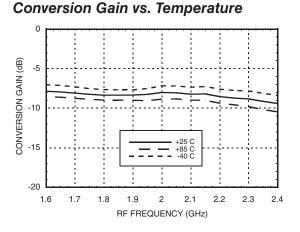
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

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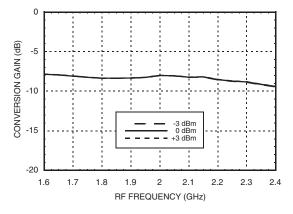


BICMOS MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 1.7 - 2.2 GHz

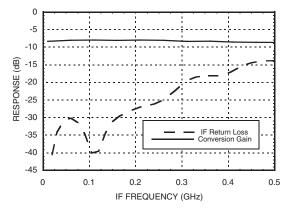


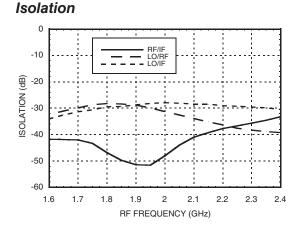
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Conversion Gain vs. LO Drive

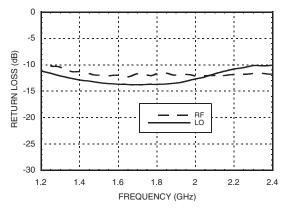


IF Bandwidth (LO= 2.2 GHz)

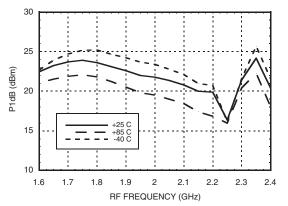




Return Loss



Input P1dB vs. Temperature



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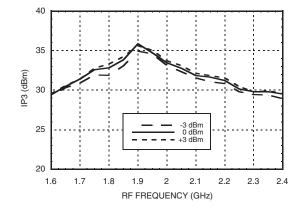
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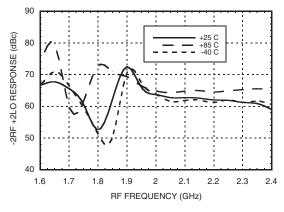
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ROHS V

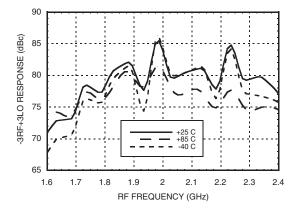
Input IP3 vs. LO Drive [1]



-2RF +2LO Response vs. Temperature [2]

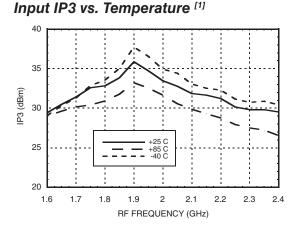


-3RF +3LO Response vs. Temperature [2]

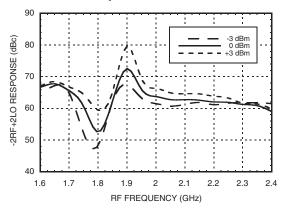


LO AMPLIFIER, 1.7 - 2.2 GHz

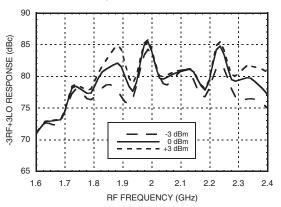
BICMOS MMIC MIXER W/ INTEGRATED



-2RF +2LO Response vs. LO Drive [2]



-3RF +3LO Response vs. LO Drive [2]



[1] Two-tone input power = +9 dBm each tone, 1 MHz spacing. [2] Referenced to RF Input power at 0 dBm

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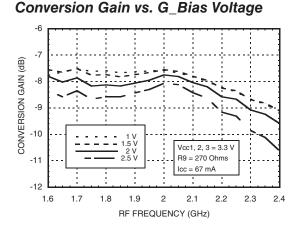




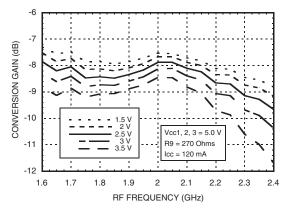
BiCMOS MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 1.7 - 2.2 GHz

Low Power Consumption Performance

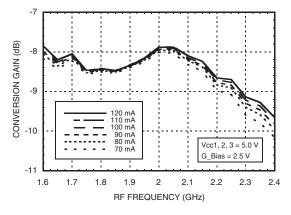
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Conversion Gain vs. G_Bias Voltage



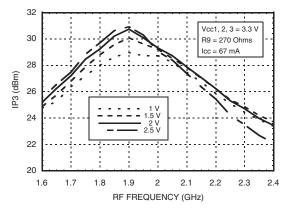
Conversion Gain vs. Icc



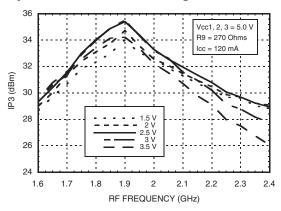
[1] Two-tone input power = +9 dBm each tone, 1 MHz spacing

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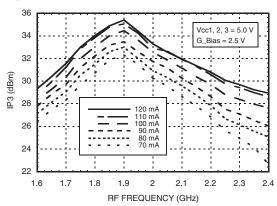
Input IP3 vs. G_Bias Voltage [1]



Input IP3 vs. G_Bias Voltage [1]



Input IP3 vs. Icc [1]



10 MIXERS - SINGLE & DOUBLE BALANCED - SMT

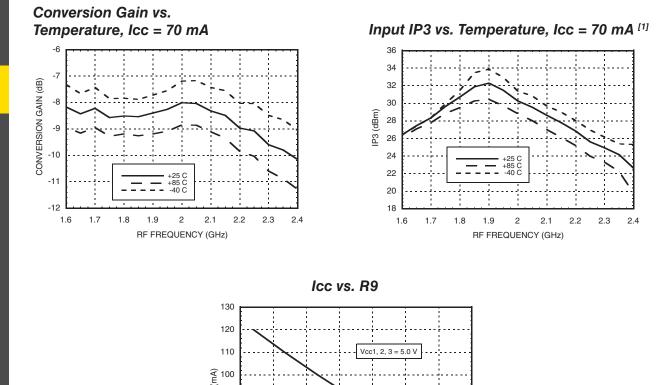


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ROHS V

BiCMOS MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 1.7 - 2.2 GHz

Low Power Consumption Performance







400

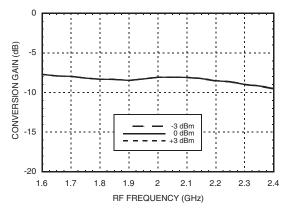
450

R9 (Ohms)

500

350

Conversion Gain vs. LO Drive



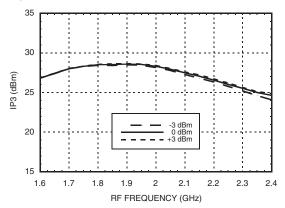
[1] Two-tone input power = +9 dBm each tone, 1 MHz spacing.

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550

600







BiCMOS MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 1.7 - 2.2 GHz

Absolute Maximum Ratings

RF / IF Input (Vcc1, 2, 3 = +5V)	+23 dBm
LO Drive (Vcc1, 2, 3 = +5V)	+10 dBm
Vcc1,2,3	+5.5V
Channel Temperature	125 °C
Continuous Pdiss (T = 85°C) (derate 20.69 mW/°C above 85°C)	0.83 mW
Thermal Resistance (channel to ground paddle)	48.33 °C/W
Storage Temperature	-65 to 150 °C
Operating Temperature	-40 to +85 °C

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ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Typical Supply Current vs. Vcc

Vcc1, 2, 3 (V)	Icc total (mA)	
4.75	113	
5.00	120	
5.25 127		
Downconverter will operate over full voltage range shown above.		

MxN Spurious @ IF Port

	nLO				
mRF	0	1	2	3	4
0	xx	20	27	54	28
1	43	0	39	31	57
2	64	60	59	68	87
3	110	81	102	77	96
4	115 129 115 115 112				
RF Freq. = 1.9 GHz @ 0 dBm LO Freq. = 2.1 GHz @ 0 dBm					

All values in dBc below IF power level (-1RF + 1LO).

Harmonics of LO

	nLO Spur @ RF Port			
LO Freq. (GHz)	1	2	3	4
1.6	37	25	46	42
1.7	35	24	44	41
1.8	33	23	43	42
1.9	30	22	36	36
2.0	29	23	40	28
2.1	29	24	44	27
2.2	32	24	42	31
2.3	34	24	42	38

LO = 0 dBm

All values in dBc below input LO level measured at RF port.

[1] Two-tone input power = +9 dBm each tone, 1 MHz spacing.

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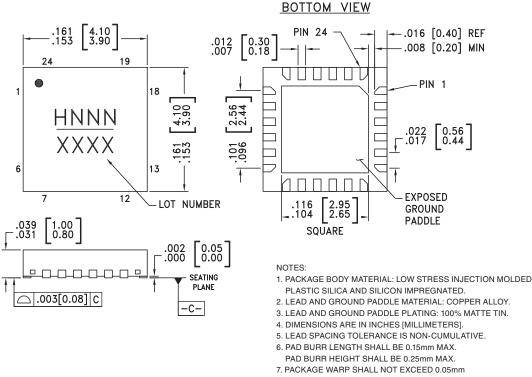


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Outline Drawing



- PACKAGE WARP SHALL NOT EXCEED 0.05mr
 ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 9. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

Package Information

Par	rt Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HM	IC687LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H687 XXXX
нмс	C687LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>H687</u> XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX



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RoHS EARTH FRIEND

BiCMOS MMIC MIXER W/ INTEGRATED LO AMPLIFIER, 1.7 - 2.2 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 6, 7, 11 - 14, 18, 20, 23	N/C	No connection. These pins may be connected to RF ground. Performance will not be affected.	
2, 5, 15, 17	GND	Package bottom must be connected to RF/DC ground.	
3	RF	This pin is matched single-ended 50 Ohm and DC shorted to ground through a balun.	
4	ТАР	Center tap of secondary side of the internal RF balun. Short to ground with a zero ohm close to the IC.	
8, 10, 24	Vcc1, Vcc2, Vcc3	Power supply voltage. See application circuit for required external components.	Vcc1-3 ESD = =
9	LO_BIAS	LO buffer current adjustment pin. Adjust the LO buffer current through the external resistor R9 shown in the application circuit (connect 270 Ohms for nominal operation). This adjustment allows for a trade-off between power dissipation and linearity performance of the converter.	LO_BIAS ESD
16	LO	This pin is matched single-ended 50 Ohm and DC shorted to ground through a balun.	
19	G_BIAS	External bias. See application circuit for recom- mended external components. Apply +2.5V for nominal operation at 5V supply voltage. G_Bias can be set to between 0 and 5Vdc. The G_bias pin has an internal 15K ohm resistance to ground. This adjustment allows for a trade off between conversion loss and linearity performance of the converter (see figures CG, IP3 vs. G-Bias).	
21, 22	IFN, IFP	Differential IF input / output pins matched to differential 50 Ohms. For applications not requiring operation to DC an off chip DC blocking capacitor should be used.	Vcc IFN I IFP I ESD I ESD I IFN I IFP I IFP I IFN

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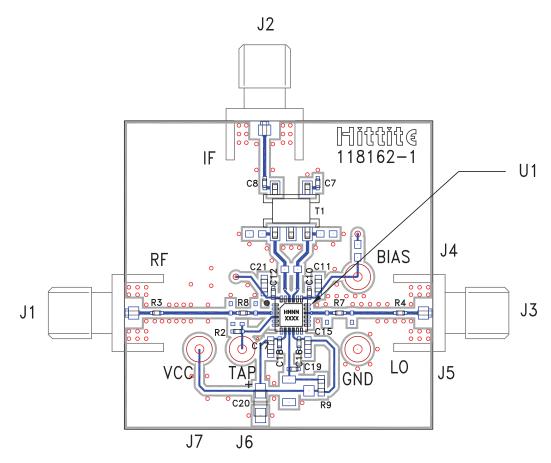
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List of Materials for Evaluation PCB 119935^[1]

Item	Description
J1 - J3	SMA Connector
J4 - J7	DC Pin
C19	22 pF Capacitor, 0402 Pkg.
C7, C8	10 nF Capacitor, 0402 Pkg.
C10, C12, C16, C18	1 nF Capacitor, 0402 Pkg.
C11, C15, C17, C21	0.1 µF Capacitor, 0402 Pkg.
C20	4.7 µF Case A, Tantulum
R2 - R4, R7, R8	0 Ohm Resistor, 0402 Pkg.
R9	270 Ohm Resistor, 0603 Pkg.
T1	1:1 Transformer - Tyco MABA CT0039
U1	HMC687LP4(E) Downconverter
PCB ^[2]	118162 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25R, FR4

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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Application Circuit C8 10nF $\left| \right|$ IF 0 C7 J2 10nF **T1** Balun 1:1 BIAS Vcc -0 0 C21 C12 C11 C10 J7 J4 0.1uF 0.1uF 1nF 1nF 24 23 22 21 20 19 18 1 R8 2 **R7** R3 17 R4 **Ο** Ω ΟΩ **0** Ω **0** Ω RF С 3 16 0 LO 3 J1 J3 4 15 TAP 5 14 R2 J6 6/ 13 Ο Ω 12 7 8 10 11 9 PACKAGE BASE GND C19 **R9** 22pF **270** Ω Vcc + C15 C20 C18 C17 C16 J7 4.7uF 1nF 0.1uF 1nF 0.1uF

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